# VCXO VG-4231CE

Product name VG-4231CE 12.000000 MHz PSC-M Product code / Ordering code Q3614CE000099xx

Please refer to the 8.Packing information about xx (last 2 digits)

Output waveform CMOS

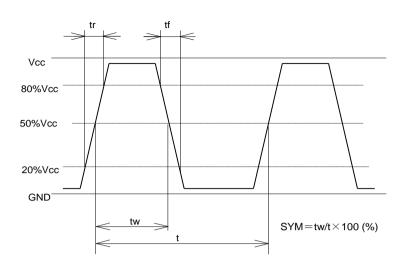
Pb free / Complies with EU RoHS directive

Reference weight Typ.26 mg

| rtereres treight rypize mg  |               |      |      |         |      |  |
|-----------------------------|---------------|------|------|---------|------|--|
| 1. Absolute maximum ratings | ximum ratings |      |      |         |      |  |
| Parameter                   | Symbol        | Min. | Тур. | Max.    | Unit | Conditions / Remarks                       |
| Maximum supply voltage      | Vcc-GND       | -0.3 | -    | +7      | V    | -  |
| Storage temperature         | T_stg         | -40  | 0    | +125    | °C   | Storage as single product after unpacking. |
| Input voltage               | Vin           | -0.3 | 0    | Vcc+0.3 | V    | Vc traminal                                |

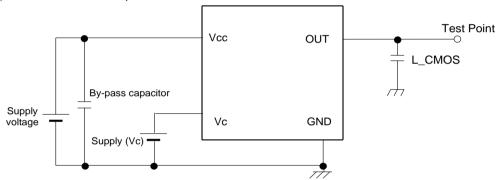
| 2.Specifications(characteristics) |                  |          |         |          |                   |                           |
|-----------------------------------|------------------|----------|---------|----------|-------------------|---------------------------|
| Parameter                         | Symbol           | Min.     | Тур.    | Max.     | Unit              | Conditions / Remarks      |
| Output frequency                  | fo               |          | 12.0000 |          | MHz               |                           |
| Supply voltage                    | Vcc              | 3        | 3.3     | 3.6      | V                 | -                         |
| Control voltage                   | Vc               | 0        | 1.65    | 3.3      | V                 | Vc=1.65V+/-1.65V          |
| Operating temperature             | T_use            | -40      | -       | +85      | ۰C                | -                         |
| Frequency tolerance               | f_tol            | -37      | -       | +37      | x10 <sup>-6</sup> | T_use                     |
| Current consumption               | Icc              | -        | •       | 2.5      | mΑ                | No load                   |
| Frequency control range           | f_cont           | +/-140   | -       | -        | x10 <sup>-6</sup> | -                         |
| Absolute pull range               | APR              | +/-95    | -       | -        | x10 <sup>-6</sup> | -                         |
| Modulation characteristics        | BW               | 15       | -       | -        | kHz               | +/-3dB                    |
| Input resistance                  | Rin              | 5        | -       | -        | МΩ                | -                         |
| Linearity                         | F <sub>LIN</sub> | 0        | 0       | 0        | %                 | 0                         |
| Frequency change polarity         | -                | Positive |         | -        | -                 |                           |
| Symmetry                          | SYM              | 40       | -       | 60       | %                 | 50% Vcc level             |
| Output voltage                    | V <sub>OH</sub>  | 90 % Vcc | -       | -        | V                 | I <sub>OH</sub> = -3.0 mA |
|                                   | $V_{OL}$         | -        | -       | 10 % Vcc | V                 | $I_{OL} = 3.0 \text{ mA}$ |
| Output load condition             | L_CMOS           | -        | •       | 15       | pF                | -                         |
| Rise time                         | tr               | -        | -       | 4        | ns                | 20%Vcc to 80%Vcc level    |
| Fall time                         | tf               | -        | -       | 4        | ns                | 80%Vcc to 20%Vcc level    |
| Start-up time                     | t_str            | -        | -       | 5        | ms                | t=0 at 90 %Vcc            |
| Frequency aging                   | f_aging          | -5       | -       | 5        | x10 <sup>-6</sup> | 25°C, 5years              |

# 3. Timing chart

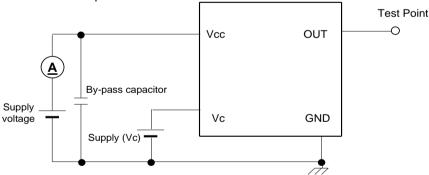


### 4.Test circuit

### 1) C-MOS load CL=15 pF

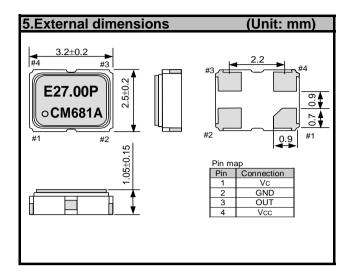


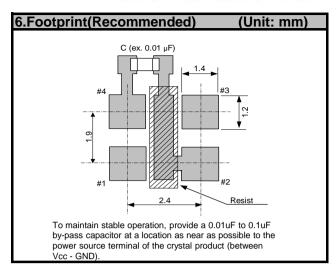
#### 2) Current consumption

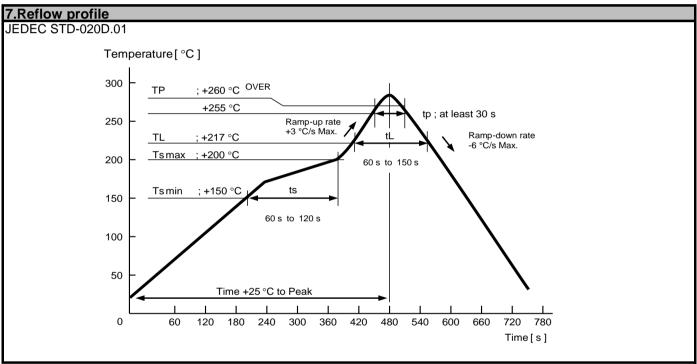


#### 3) Condition

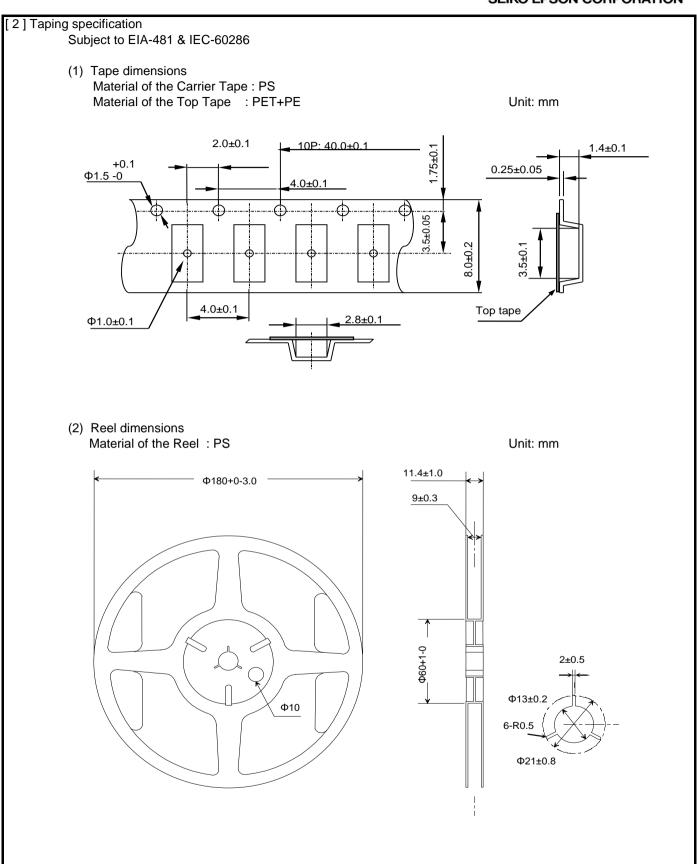
- 1. Oscilloscope
  - Impossible to measure both frequency and wave form at the same time.
    (In case of using oscilloscope's amplifier output, possible to measure both at the same time.)
- 2. L\_CMOS includes probe capacitance.
- 3. By-pass capacitor (0.01  $\mu F$  to 0.1  $\mu F)$  is placed closely between Vcc and GND.
- 4. Use the current meter whose internal impedance value is small.
- 5. Power Supply
  - ·Start up time (0 %Vcc→90 %Vcc) of power source should be more than 150 µs.
- ·Impedance of power supply should be as low as possible.
- 6. One point earth of test cirouit is required.







| 8.Packing  | informa | tion                         |      |               |  |
|--|---------|------------------------------|------|---------------|--|
| [ 1 ]Product number last 2 digits code(xx) description |         |                              |      |               |  |
|  | Q3614CE | 000099xx                     |      |               |  |
|  | Code    | Condition                    | Code | Condition     |  |
|  | 00      | 1000pcs / Reel               | 12   | 250pcs / Reel |  |
|  | 01      | Any Q'ty vinyl bag(Tape cut) | 13   | 500pcs / Reel |  |
|  | 11      | Any Q'ty / Reel              | 14   | 1kpcs / Reel  |  |
|  |         |                              |      | -             |  |



#### 9.Notice

- This material is subject to change without notice.
- Any part of this material may not be reproduced or duplicated in any form or any means without the written permission of Seiko Epson.
- The information about applied circuitry, software, usage, etc. written in this material is intended for reference only. Seiko Epson does not assume any liability for the occurrence of infringing on any patent or copyright of a third party. This material does not authorize the licensing for any patent or intellectual copyrights.
- When exporting the products or technology described in this material, you should comply with the applicable export control laws and regulations and follow the procedures required by such laws and regulations.
- You are requested not to use the products (and any technical information furnished, if any) for the development and/or manufacture of weapon of mass destruction or for other military purposes. You are also requested that you would not make the products available to any third party who may use the products for such prohibited purposes.
- These products are intended for general use in electronic equipment. When using them in specific applications that require extremely high reliability, such as the applications stated below, you must obtain permission from Seiko Epson in advance.
  - / Space equipment (artificial satellites, rockets, etc.)
  - / Transportation vehicles and related (automobiles, aircraft, trains, vessels, etc.)
  - / Medical instruments to sustain life
  - / Submarine transmitters
  - / Power stations and related
  - / Fire work equipment and security equipment
  - / Traffic control equipment
  - / And others requiring equivalent reliability.
- All brands or product names mentioned herein are trademarks and/or registered trademarks of their respective.

## 10.Contact us

http://www5.epsondevice.com/en/contact/